# NSN 5962-01-227-8294

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

1.250 inches

# **Body Width:**

Between 0.220 inches and 0.310 inches

# **Body Height:**

0.140 inches

## **Operating Tempurature Range:**

-55.0 to 100.0 degrees celsius

## Storage Tempurature Range:

-65.0 to 125.0 degrees celsius

## **Features Provided:**

Programmable and erasable and hermetically sealed and w/enable and electrostatic sensitive

## Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

N-type metal oxide-semiconductor logic

## Input Circuit Pattern:

14 input

Case Outline Source And Designator:

D-9 mil-m-38510

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

6.0 volts power source and 26.5 volts power source

# **Time Rating Per Chacteristic:**

450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

#### Fiig:

A458a0